

v02.0121

GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 5 - 18 GHz

Typical Applications

The HMC451LP3(E) is ideal for:

- Microwave Radio & VSAT
- Military & Space
- Test Equipment & Sensors
- Fiber Optics
- LO Driver for HMC Mixers

Features

Gain: 18 dB

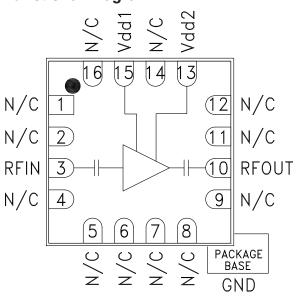
Saturated Power: +21 dBm @ 18% PAE

Output IP3: +28 dBm

Single Supply: +5V @ 120 mA 50 Ohm Matched Input/Output

16 Lead 3x3mm SMT Package: 9mm²

Functional Diagram



General Description

The HMC451LP3(E) is an efficient GaAs PHEMT MMIC Medium Power Amplifier housed in a leadless RoHS compliant SMT package. Operating between 5 and 18 GHz, the amplifier provides 18 dB of gain, +21 dBm of saturated power and 18% PAE from a single +5V supply. This 50 Ohm matched amplifier does not require any external components and the RF I/O's are DC blocked, making it an ideal linear gain block or LO driver for HMC mixers. The HMC451LP3(E) eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

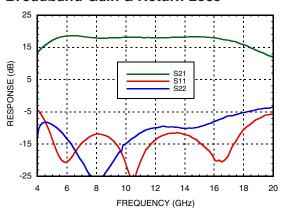
Electrical Specifications, $T_A = +25^{\circ} \text{ C}$, $Vdd_1 = Vdd_2 = +5V$

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	5 - 16		16 - 18			GHz	
Gain	15	18		12.5	16		dB
Gain Variation Over Temperature		0.02	0.03		0.02	0.03	dB/ °C
Input Return Loss		13			13		dB
Output Return Loss		12			8		dB
Output Power for 1 dB Compression (P1dB)	16.5	19.5		16	19		dBm
Saturated Output Power (Psat)		21			20		dBm
Output Third Order Intercept (IP3)		28			25		dBm
Noise Figure		7			7		dB
Supply Current (Idd)		120	150		120	150	mA

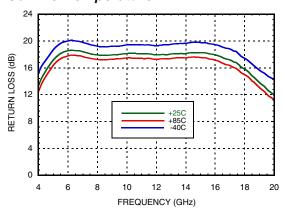


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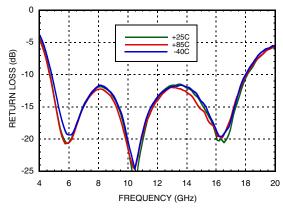
Broadband Gain & Return Loss



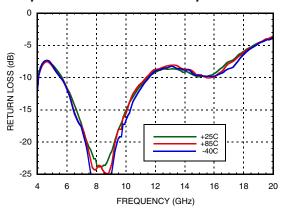
Gain vs. Temperature



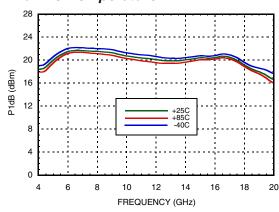
Input Return Loss vs. Temperature



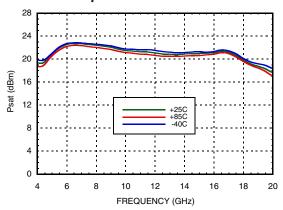
Output Return Loss vs. Temperature



P1dB vs. Temperature



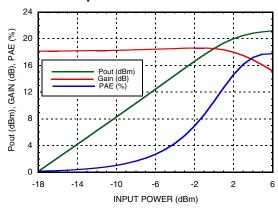
Psat vs. Temperature



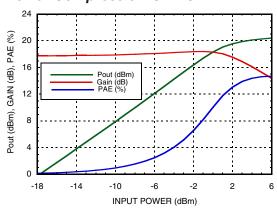


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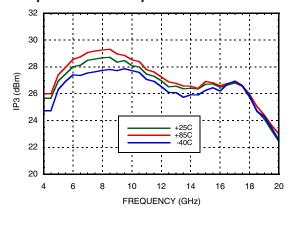
Power Compression @ 10 GHz



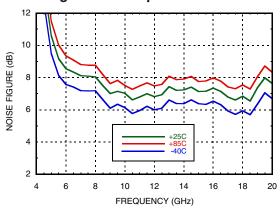
Power Compression @ 17 GHz



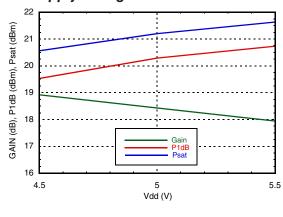
Output IP3 vs. Temperature



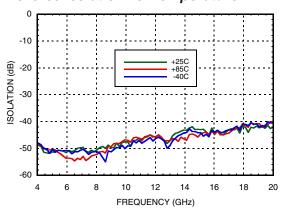
Noise Figure vs. Temperature



Gain, P1dB & PSAT vs. Supply Voltage @ 11 GHz



Reverse Isolation vs. Temperature





HMC451LP3 / 451LP3E

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Absolute Maximum Ratings

Drain Bias Voltage (Vdd ₁ = Vdd ₂)	+5.5V
RF Input Power (RFIN)(Vdd = +5Vdc)	+10 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85 °C) (derate 12.8 mW/°C above 85 °C)	1.15 W
Thermal Resistance (channel to ground paddle)	78 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A, passed 250V

Typical Supply Current vs. $Vdd_1 = Vdd_2$

$Vdd_1 = Vdd_2(V)$	$Idd_1 + Idd_2 (mA)$
+4.5	120
+5.0	122
+5.5	124

Note: Amplifier will operate over full voltage range shown above



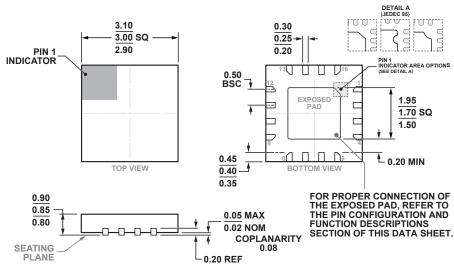


HMC451LP3 / 451LP3E

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GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 5 - 18 GHz

Outline Drawing - HMC451LP3



COMPLIANT WITH JEDEC STANDARDS MO-220-VEED-4.

16-Lead Lead Frame chip Scale Package [LFCSP] 3 mm × 3 mm Body and 0.85 mm Package Height (HCP-16-1)

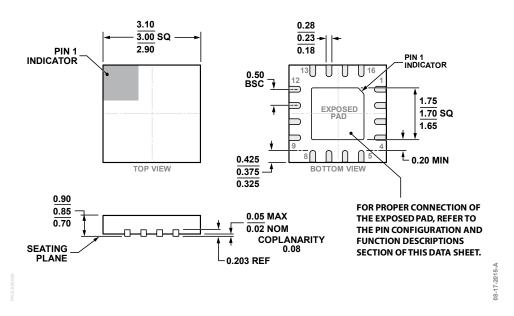
Dimensions shown in millimeters.



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GaAs PHEMT MMIC MEDIUM POWER AMPLIFIER, 5 - 18 GHz

Outline Drawing - HMC451LP3E



16-Lead Lead Frame chip Scale Package [LFCSP] 3 mm × 3 mm Body and 0.85 mm Package Height (HCP-16-3) Dimensions shown in millimeters.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC451LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H451 XXXX
HMC451LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	4 <u>51</u> XXXX

^[1] Max peak reflow temperature of 235 °C

^[2] Max peak reflow temperature of 260 °C

^{[3] 4-}Digit lot number XXXX



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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 2, 4 - 9, 11, 12, 14, 16	N/C	This pin may be connected to RF/DC ground. Performance will not be affected.	
3	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN ○── ├──
10	RFOUT	This pin is AC coupled and matched to 50 Ohms.	—
13	Vdd2	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd2
15	Vdd1	Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd1
	GND	Package bottom must be connected to RF/DC ground.	GND =

Application Circuit

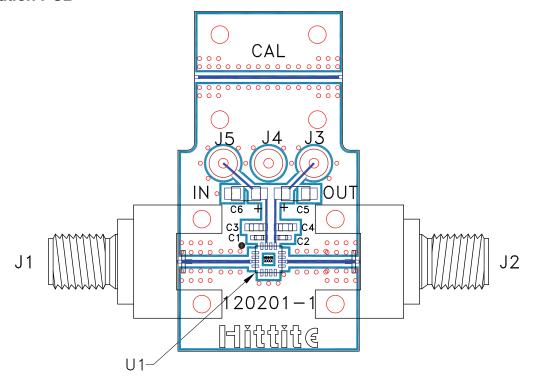
Component	Value	J5 ♀ Vdd1
C1, C2	100 pF	
C3, C4	1,000 pF	C1 + C3 + C6 +
C5, C6	2.2 µF]
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Evaluation PCB



List of Materials for Evaluation PCB 120202 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	1000 pF Capacitor, 0603 Pkg.
C5, C6	2.2 µF Capacitor, Tantalum
U1	HMC451LP3(E) Amplifier
PCB [2]	120201 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices, upon request.

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